

KSA992

Audio Frequency Low Noise Amplifier

Complement to KSC1845



1. Emitter 2. Collector 3. Base

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	-120	V
V _{CEO}	Collector-Emitter Voltage	-120	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-50	mA
I _B	Base Current	-10	mA
P _C	Collector Power Dissipation	500	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CBO}	Collector Cut-off Current	$V_{CB} = -120V, I_{E} = 0$			-50	nA
I _{CEO}	Collector Cur-off Current	V _{CE} = -100V, I _B =0			-1	μΑ
I _{EBO}	Emitter Cut-off Current	V_{EB} = -5mA, I_{C} =0			-50	nA
h _{FE1}	DC Current Gain	V_{CE} = -6V, I_{C} = -0.1mA V_{CE} = -6V, I_{C} = -1mA	150 200	500 500	800	
V _{BE} (on)	Base-Emitter On Voltage	V_{CE} = -6V, I_{C} = -1mA	-0.55	-0.61	-0.65	V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -10mA, I _B = -1mA		-0.09	-0.3	V
f _T	Current Gain Bandwidth Product	V_{CE} = -6V, I_{C} = -1mA	50	100		MHz
C _{ob}	Output Capacitance	V_{CB} = -30V, I_{E} =0, f=1MHz		2	3	pF
NV	Noise Voltage	$V_{CE} = -5.0V, I_{C} = -1.0mA,$ $R_{G} = 100KW, G_{V} = 80dB,$ f = 10Hz to 1.0KHz		25	40	mV

h_{FE2} Classification

Classification	Р	F	Е	
h _{FE2}	200 ~ 400	300 ~ 600	400 ~ 800	

Typical Characteristics

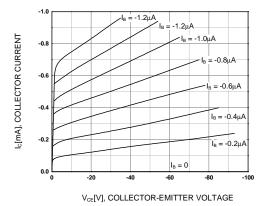


Figure 1. Static Characteristic

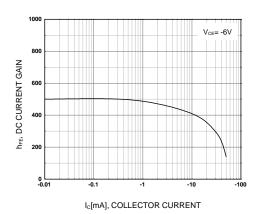


Figure 3. DC current Gain

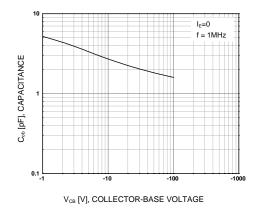


Figure 5. Collector Output Capacitance

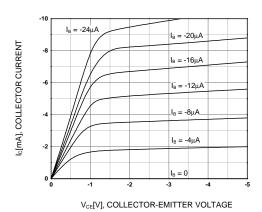


Figure 2. Static Characteristic

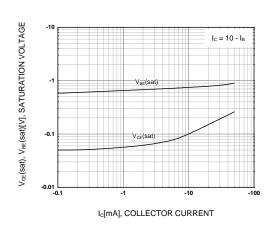


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

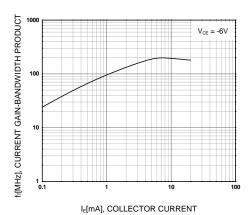


Figure 6. Current Gain Bandwidth Product

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Typical Characteristics (Continued)

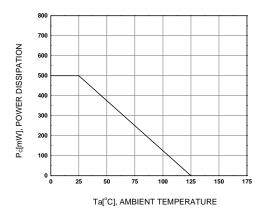
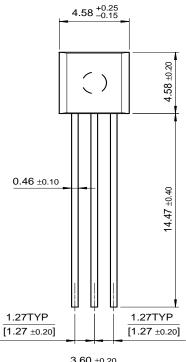
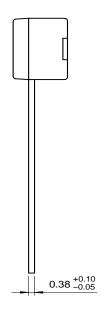


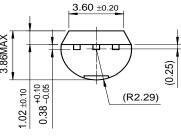
Figure 7. Power Derating

Package Dimensions

TO-92







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FACT Quiet Series™	I	OPTOLOGIC [®]	SILENT SWITCHER®	VCX™
Across the board. Ar	ound the world.™	OPTOPLANAR™	SMART START™	
The Power Franchise	e [®]	PACMAN™	SPM™	
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